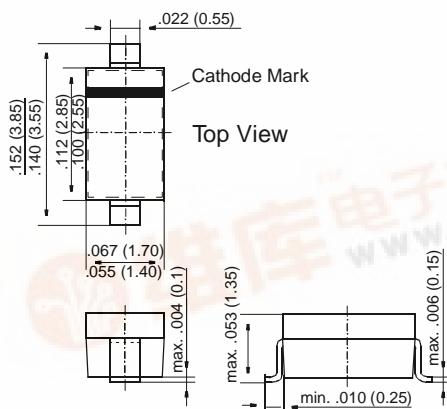


BAT46W

Schottky Diodes

SOD-123



Dimensions in inches and (millimeters)

FEATURES

- ◆ For general purpose applications.
- ◆ These diodes feature very low turn-on voltage and fast switching. These devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges.
- ◆ This diode is also available in the DO-35 case with type designation BAT46 and in the MiniMELF case with type designations LL46.



MECHANICAL DATA

Case: SOD-123 Plastic Case

Weight: approx. 0.01 g

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V _{RRM}	100	V
Forward Continuous Current at T _{amb} = 25 °C	I _F	150 ²⁾	mA
Repetitive Peak Forward Current at t _p < 1 s, δ < 0.5, T _{amb} = 25 °C	I _{FRM}	350 ²⁾	mA
Surge Forward Current at t _p < 10 ms, T _{amb} = 25 °C	I _{FSM}	750 ²⁾	mA
Power Dissipation ¹⁾ at T _{amb} = 65 °C	P _{tot}	150 ²⁾	mW
Junction Temperature	T _j	125	°C
Ambient Operating Temperature Range	T _{amb}	-55 to +125	°C
Storage Temperature Range	T _s	-55 to +150	°C

²⁾ Valid provided that electrodes are kept at ambient temperature



BAT46W

ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

	Symbol	Min.	Typ.	Max.	Unit
Reverse Breakdown Voltage tested with 100 µA Pulses	$V_{(BR)R}$	100	—	—	V
Forward Voltage Pulse Test $t_p < 300 \mu s$, $\delta < 2\%$ at $I_F = 0.1 \text{ mA}$ at $I_F = 10 \text{ mA}$ at $I_F = 250 \text{ mA}$	V_F V_F V_F	— — —	— — —	0.25 0.45 1	V V V
Leakage Current Pulse Test $t_p < 300 \mu s$, $\delta < 2\%$ at $V_R = 1.5 \text{ V}$ at $V_R = 1.5 \text{ V}$, $T_j = 60 \text{ }^\circ\text{C}$ at $V_R = 10 \text{ V}$ at $V_R = 10 \text{ V}$, $T_j = 60 \text{ }^\circ\text{C}$ at $V_R = 50 \text{ V}$ at $V_R = 50 \text{ V}$, $T_j = 60 \text{ }^\circ\text{C}$ at $V_R = 75 \text{ V}$ at $V_R = 75 \text{ V}$, $T_j = 60 \text{ }^\circ\text{C}$	I_R I_R I_R I_R I_R I_R I_R I_R	— — — — — — — —	— — — — — — — —	0.5 5 0.8 7.5 2 15 5 20	μA μA μA μA μA μA μA μA
Capacitance at $V_R = 0 \text{ V}$, $f = 1 \text{ MHz}$ at $V_R = 1 \text{ V}$, $f = 1 \text{ MHz}$	C_{tot} C_{tot}	— —	10 6	— —	pF pF
Thermal Resistance Junction to Ambient Air	R_{thJA}	—	—	0.3 ²⁾	K/mW

²⁾ Valid provided that electrodes are kept at ambient temperature